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TOSHIBA Photocoupler Photorelay

# TLP4197G

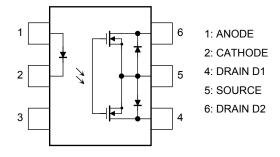
PBX Telecommunication Modem · FAX Cards, Modems In PC Measurement Instrumentation

The TOSHIBA TLP4197G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a SOP, which is suitable for surface mount assembly.

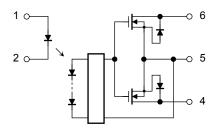
The TLP4197GA is suitable for replacement of mechanical relays in many applications which require space savings.

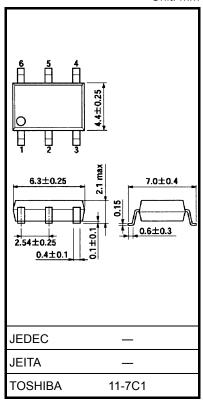
- 6 pin SOP (2.54SOP6): 2.1 mm high, 2.54 mm pitch
- 1-form-B
- Peak off-state voltage: 350 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 120 mA (max)
- On-state resistance:  $25 \Omega$  (max)
- Isolation voltage: 1500 Vrms (min)

#### Pin Configuration (top view)



#### Schematic





Weight: 0.13 g (typ.)

#### Absolute Maximum Ratings (Ta = 25°C)

	Characteris	tics	Symbol	Rating	Unit
LED	Forward current		١ <sub>F</sub>	50	mA
	Forward current derating $(Ta \ge 25^{\circ}C)$		∆l <sub>F</sub> /°C	-0.5	mA/°C
	Peak forward current (100 μs pulse, 100 pps)		I <sub>FP</sub>	1	А
	Reverse voltage		VR	5	V
	Junction temperat	ure	Тj	125	°C
	Off-state output terminal voltage		VOFF	350	V
	On-state current	A connection	I <sub>ON</sub>	120	
		B connection		120	mA
ector		C connection		240	
Detector	On-state current derating (Ta ≧ 25°C)	A connection		-1.2	
		B connection	∆l <sub>ON</sub> /°C	-1.2	mA/°C
		C connection		-2.4	
	Junction temperat	ure	Tj	125	°C
Ope	Operating temperature range		T <sub>opr</sub>	-40 to 85	°C
Storage temperature range			T <sub>stg</sub>	-55 to 125	°C
Lead	d soldering tempera	ture (10 s)	T <sub>sol</sub>	260	°C
Isola (AC,	tion voltage 1 min, R.H. ≦ 60%	) (Note 1)	BVS	1500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

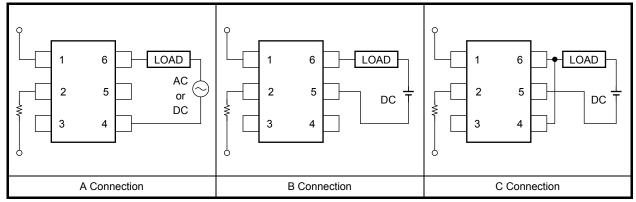
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Recommended Operating Conditions**

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V <sub>DD</sub>	_	—	280	V
Forward current	١ <sub>F</sub>	5	_	25	mA
On-state current	ION		_	120	mA
Operating temperature	T <sub>opr</sub>	-20		65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

#### **Circuit Connections**



Note 1: Device considered a two-terminal device: LED side pins shorted together, and DETECTOR side pins and 6 shorted together.

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#### Individual Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
LED	Forward voltage	VF	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
	Reverse current	I <sub>R</sub>	$V_R = 5 V$	_	_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz	_	30	_	pF
Detec- tor	Off-state current	I <sub>OFF</sub>	$V_{OFF} = 350 \text{ V}, \text{ I}_F = 5 \text{ mA}$	_	_	1	μA
	Capacitance	C <sub>OFF</sub>	$V=0,f=1MHz,I_F=5mA$				pF

#### **Coupled Electrical Characteristics** (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current		I <sub>FC</sub>	I <sub>OFF</sub> = 10 μA	_	1	3	mA
Return LED current		I <sub>FT</sub>	I <sub>ON</sub> = 120 mA	0.1	_	_	mA
	A connection	R <sub>ON</sub>	I <sub>ON</sub> = 120 mA	_	15	25	
On-state resistance	B connection		I <sub>ON</sub> = 120 mA	_	8	14	Ω
	C connection		I <sub>ON</sub> = 240 mA	_	4	_	

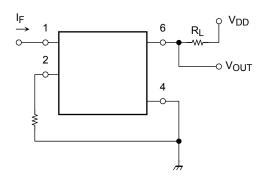
#### Isolation Characteristics (Ta = 25°C)

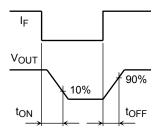
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	$V_S = 0, f = 1 MHz$		0.8	_	pF
Isolation resistance	R <sub>S</sub>	$V_S = 500 \text{ V}, \text{ R.H.} \leq 60\%$	$5  imes 10^{10}$	10 <sup>14</sup>	_	Ω
	BVS	AC, 1 min	1500	_	_	Vrms
Isolation voltage		AC, 1 s, in oil		3000	_	
		DC, 1 min, in oil	—	3000	_	Vdc

#### Switching Characteristics (Ta = 25°C)

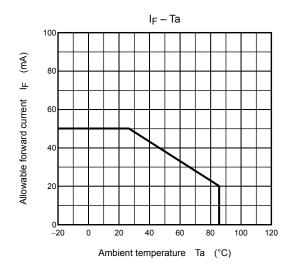
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t <sub>ON</sub>	$R_L = 200 \Omega$ (Note 2)			1	ms
Turn-off time	tOFF	$V_{DD} = 20 \text{ V}, \text{ I}_{\text{F}} = 5 \text{ mA}$	_		3	ms

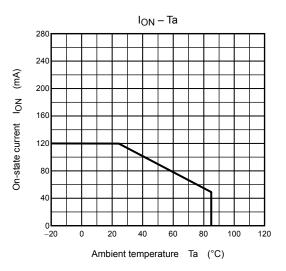
Note 2: Switching time test circuit

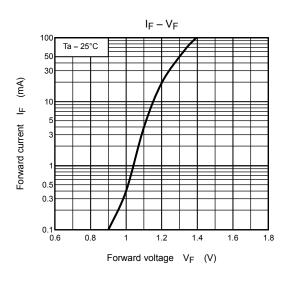


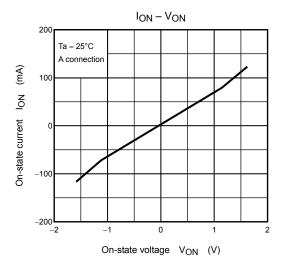


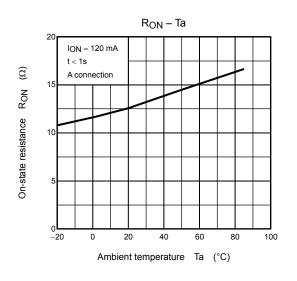
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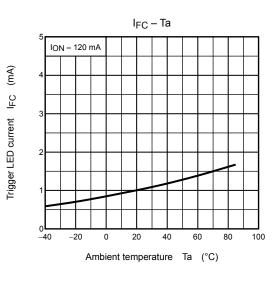




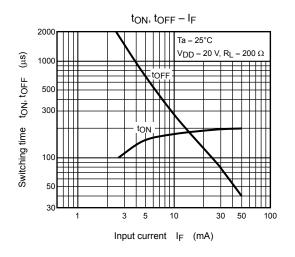


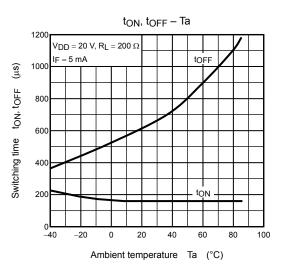


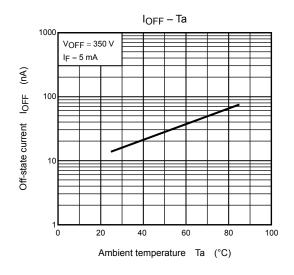




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